

Photo DMOS-FET Relay

Description

The **LTU720** is a 1-From A and 1-Form B solid state relay in a 8 pin SMD package that employs optically coupled MOSFET technology to provide 3750V of input to output isolation. The optically coupled input is controlled by a highly efficient GaAlAs infrared LED and MOS FETs on the output side.

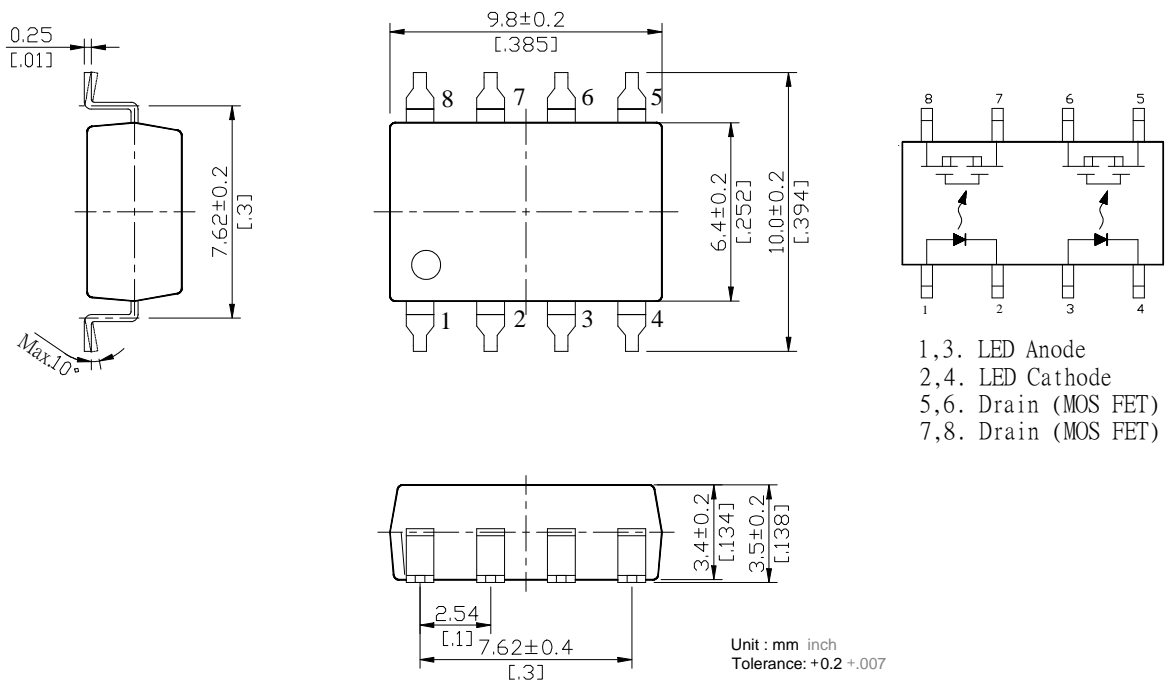
Features

- Low driver power requirements (TTL/CMOS Compatible)
- No moving parts
- High reliability
- Arc-Free with no snubbing circuits
- 3750Vrms Input/Output isolation

Applications

- Telecommunications (PC, Electronic notepad)
- Measuring and Testing equipment
- Industrial control
- Security equipments
- High speed inspection machine

Outline Dimensions



- 1,3. LED Anode
- 2,4. LED Cathode
- 5,6. Drain (MOS FET)
- 7,8. Drain (MOS FET)

Photo DMOS-FET Relay Specifications

Part Name: LTU720

Absolute Maximum Ratings (Ambient Temperature: 25°C)

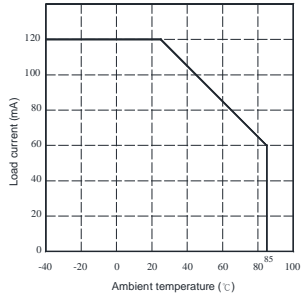
Item		Symbol	Value	Units	Note
Input	Continuous LED Current	IF	50	mA	
	Peak LED Current	IFP	1000	mA	f=100Hz, duty=1%
	LED Reverse Voltage	VR	5	V	
	Input Power Dissipation	PIn	75	mW	
Output	Load Voltage	VL	400	V(AC peak or DC)	
	Load Current	IL	120	mA	
	Peak Load Current	I _{Peak}	0.6	A	1ms(1 pulse)
	Output Power Dissipation	P _{out}	450	mW	
Total Power Dissipation		PT	500	mW	
I/O Breakdown Voltage		VI/O	3750	V _{rms}	RH=60%, 1min
Operating Temperature		T _{opr}	-40 to +85	-40 to +85	
Storage Temperature		T _{stg}	-40 to +100	-40 to +100	
Pin Soldering Temperature		T _{sol}	260	260	10 sec max.

Electrical Specifications (Ambient Temperature: 25°C)

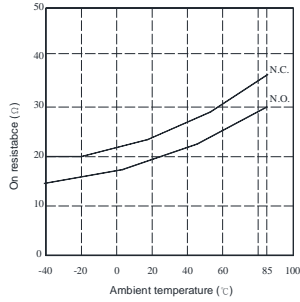
Item		Symbol	MIN.	TYP.	MAX.	Units	Conditions
Input	LED Forward Voltage	V _F		1.2	1.5	V	I _F =10mA
	Operation LED Current	I _{F On}		0.5	5.0	mA	
	Recovery LED Current	I _{F Off}		0.35	0.5	mA	
	Recovery LED Voltage	V _{F Off}	0.5			V	
Output	On-Resistance	R _{On}		20(N.O.) 20(N.C.)	30(N.O.) 50(N.C.)	Ω	I _F =5mA (N.O.) I _F =0mA (N.C) I _L =100mA Time to flow is within 1 sec.
	Off-State Leakage Current	I _{Leak}			1(N.O.) 10(N.C.)	uA	I _F =0mA (N.O.) I _F =5mA (N.C) V _L = Rating
	Output Capacitance	C _{Out}		150		pF	I _F =5mA, V _L =0, f=1MHz
Transmission	Turn-On Time	T _{On}		0.23(N.O.) 0.2(N.C.)	0.5(N.O.) 1.0(N.C.)	ms	I _F =5mA, I _L =50mA
	Turn-Off Time	T _{Off}		0.03(N.O.) 0.5(N.C.)	0.2(N.O.) 3.0(N.C.)	ms	
Coupled	I/O Isolation Resistance	R _{I/O}	10 ¹⁰			Ω	DC500V
	I/O Capacitance	C _{I/O}		0.8		pF	f=1MHz

Reference Data

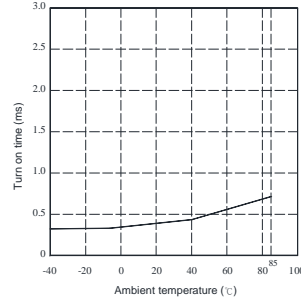
Load current Vs. Ambient temperature



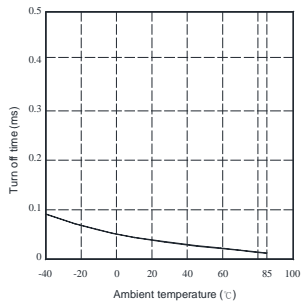
On resistance Vs. Ambient temperature



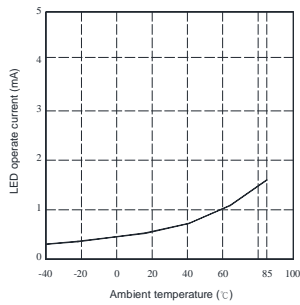
Turn off time Vs. Ambient temperature



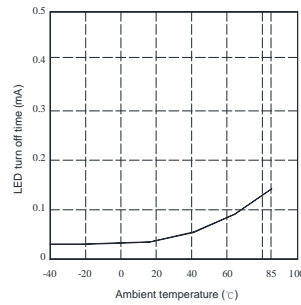
Turn on time Vs. Ambient temperature



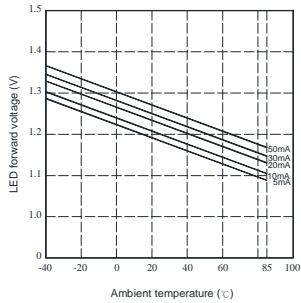
LED operate current Vs. Ambient temperature



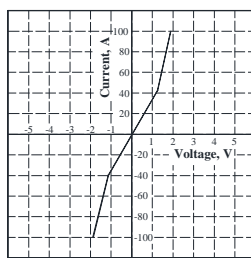
LED turn off current Vs. Ambient temperature



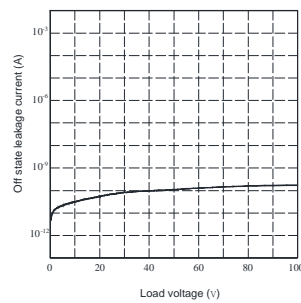
LED forward voltage Vs. Ambient temperature



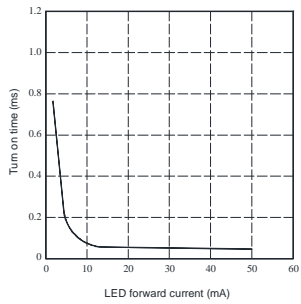
Voltage Vs. current characteristics of output at MOS portion



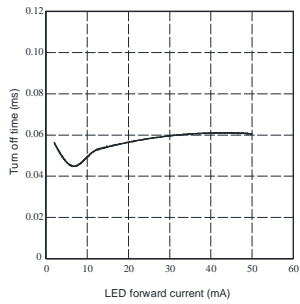
Off state leakage current



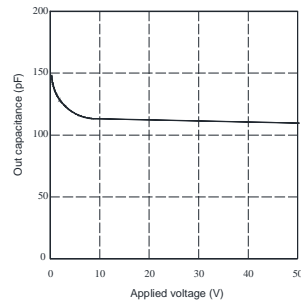
LED forward current Vs. turn on time characteristics



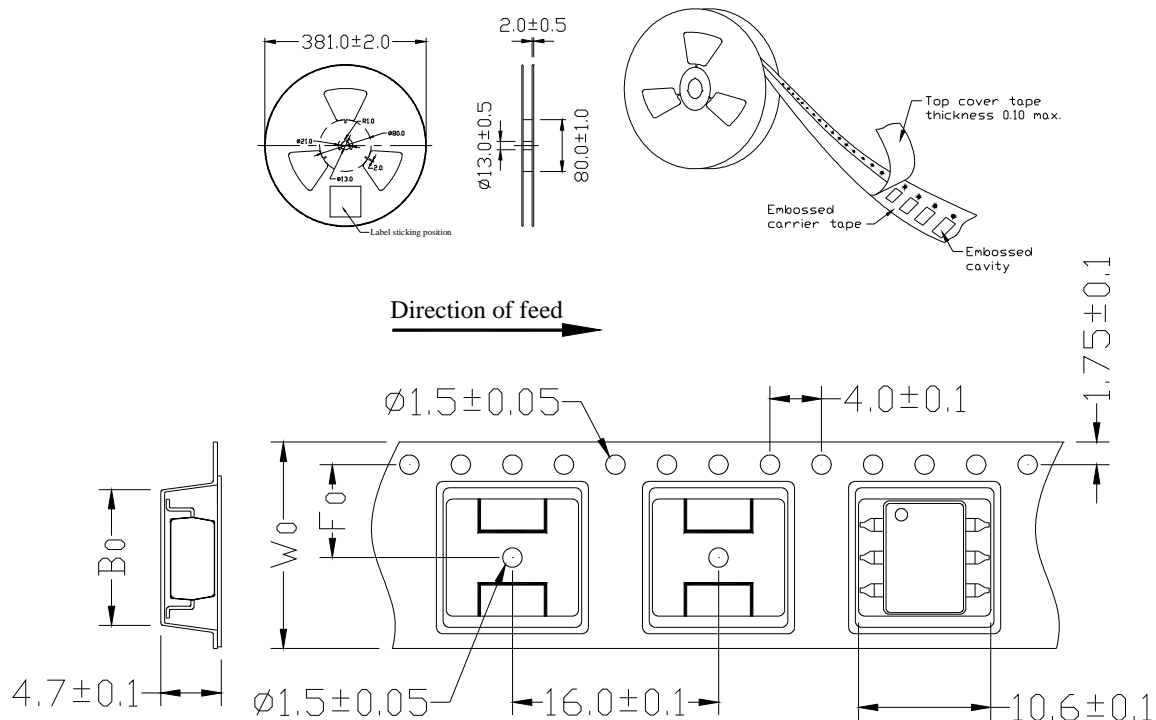
LED forward current Vs. turn off time characteristics



Applied voltage Vs. output capacitance characteristics



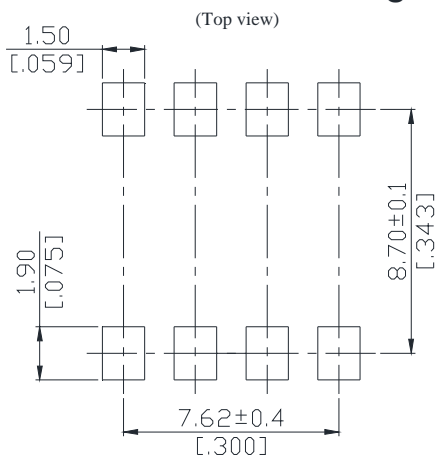
Taping Specifications for Surface Mount Devices



Unit: mm

TYPE	B0±0.1	F0±0.1	W0±0.1	13"REEL/PCS
4P	5.3	7.5	16	1000
6P	9.4	7.5	16	1000
8P	10.3	11.5	24	1000

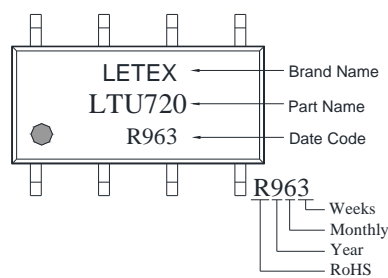
Recommended Mounting Pad



Unit : mm [inch]
Tolerance : ±0.1

Marking

(Each photo MOS Relay shall be marked with the following information)



- Note: 1. There shall be leader of 230 mm minimum which may consist of carrier and or cover tape follower by a minimum of 160 mm of carrier tape sealed with cover tape.
2. There shall be a minimum of 160 mm of empty component pockets sealed with cover tape.
3. Devices are pockets in accordance with EIA standard EIA-481-A and specifications given above.